

PMEG3010EB

1 A very low VF MEGA Schottky barrier rectifier Rev. 2 — 15 March 2012 Pro

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD523 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Forward current: I_F ≤ 1 A
- Reverse voltage: V_R ≤ 30 V
- Very low forward voltage
- AEC-Q101 qualified
- Ultra small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Quick reference data Table 1.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	T _{sp} ≤ 55 °C	-	-	1	Α
V_R	reverse voltage		-	-	30	V
V _F	forward voltage	I_F = 1 A; pulsed; $t_p \le 300~\mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	610	680	mV

Pinning information 2.

Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		
2	Α	anode	1 2	1 [2 2 sym001
			SOD523	

^[1] The marking bar indicates the cathode.



3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMEG3010EB	-	plastic surface-mounted package; 2 leads	SOD523			

4. Marking

Table 4. Marking codes

Type number	Marking code
PMEG3010EB	KA

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage			-	30	V
I _F	forward current	T _{sp} ≤ 55 °C		-	1	Α
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.25$		-	3	Α
I _{FSM}	non-repetitive peak forward current	$t_p = 8 \text{ ms}; T_{j(init)} = 25 \text{ °C}; \text{ square wave}$		-	5	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	<u>[1]</u>	-	310	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1][2]</u>	-	-	400	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[3]	-	-	75	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

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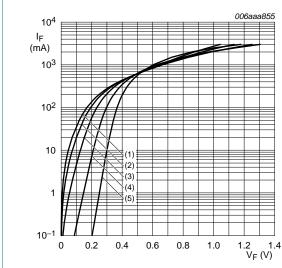
^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Soldering point of cathode tab.

7. Characteristics

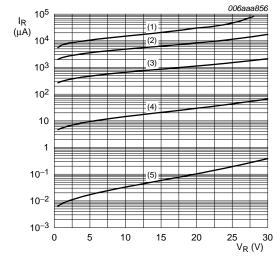
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I_F = 0.1 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	90	180	mV
		I_F = 1 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	150	200	mV
		I_F = 10 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	210	270	mV
		I_F = 100 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	295	360	mV
		I_F = 500 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	430	500	mV
		I_F = 1 A; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	-	610	680	mV
I _R	reverse current	$V_R = 10 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$	-	15	200	μΑ
		V _R = 30 V; T _{amb} = 25 °C	-	70	500	μΑ
C _d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$; $T_{amb} = 25 °C$	-	24	30	pF



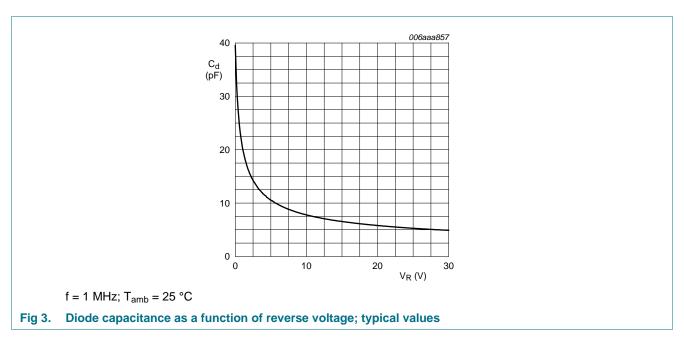
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 125 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \, ^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values

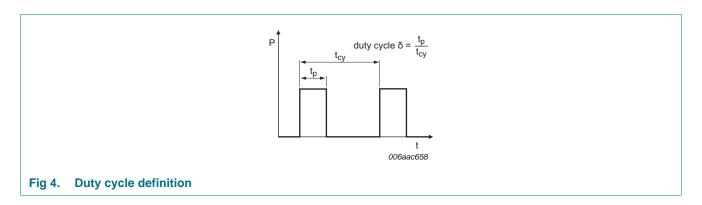


- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 125 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \, ^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



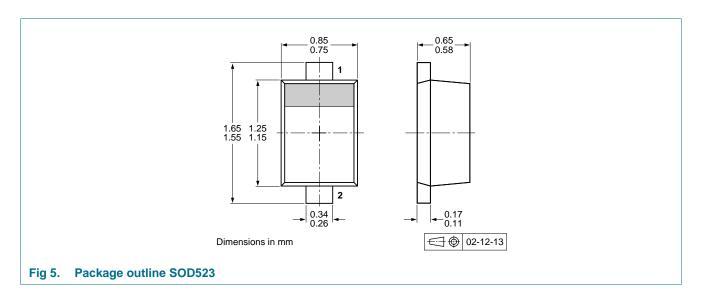
8. Test information



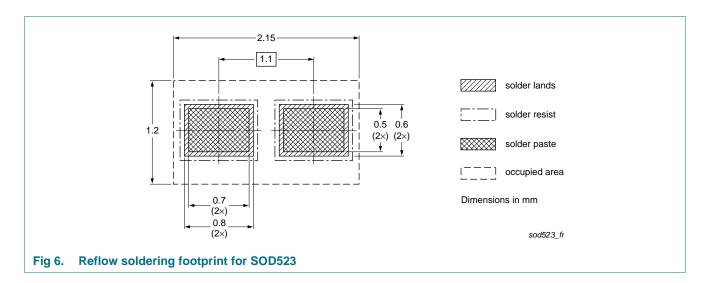
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline



10. Soldering



11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3010EB v.2	20120315	Product data sheet	-	PMEG3010EB v.1
Modifications: • 1 "Product profile • 5 "Limiting value • 8 "Test information		ues":I _{FRM} and I _{FSM} values c	orrected	
PMEG3010EB v.1	20061201	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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